

	Type	L #	Hits	Search Text	DBs	Comments
1	BRS	L1	147140	438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
2	BRS	L2	47215	1 and (transistor or MOS or FET or MOSFET)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
3	BRS	L3	5475	2 and (metal or Co or cobalt) near (silicide or salicide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
4	BRS	L4	1	3 and (source near limit\$3 near manner)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
5	BRS	L5	0	3 and (metal near silicide near crawl)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
6	BRS	L6	1031	3 and sheet near resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
7	BRS	L7	0	6 and (metal near deposit\$3 near parameter)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
8	BRS	L9	0	8 and (source near limit\$3 near manner)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
9	BRS	L8	4	gadepally-kamesh-v.in .	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
10	BRS	L11	0	(source near limit\$3 near salicidation).ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
11	BRS	L12	16801	(metal or Co or cobalt) near (silicide or salicide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
12	BRS	L13	0	12 and (source near limit\$3 near salicidation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
13	BRS	L14	54	12 and (source near limit\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
14	BRS	L15	0	14 and (metal near deposit\$3 near parameter)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
15	BRS	L16	0	15 and (metal near silicide near crawl)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	
16	BRS	L18	5	14 and sheet near resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	